

2N5655G Information



For Reference Only

Part Number 2N5655G

Manufacturer ON Semiconductor

Category Discrete Semiconductor Products

Transistors - Bipolar (BJT) - Single

Description TRANS NPN 250V 0.5A TO225AA

Package TO-225AA, TO-126-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









2N5655G Specifications

Manufacturer Part Number	2N5655G
Manufacturer	ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-225AA, TO-126-3
Series	-
Transistor Type	NPN
Current - Collector (Ic) (Max)	500mA
Voltage - Collector Emitter Breakdown (Max)	250V
Vce Saturation (Max) @ Ib, Ic	10V @ 100mA, 500mA
Current - Collector Cutoff (Max)	100μΑ
DC Current Gain (hFE) (Min) @ Ic, Vce	30 @ 100mA, 10mV
Power - Max	20W
Frequency - Transition	10MHz
Operating Temperature	-65°C ~ 150°C (TJ)
Mounting Type	Through Hole
Package / Case	TO-225AA, TO-126-3
Supplier Device Package	TO-225AA
	Report errors?

2N5655G Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

2N5655G Payment Methods





















2N5655G Shipping Methods













If you have any question about 2N5655G, please do not hesitate to contact us!

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